

## Fast Recovery Epitaxial Diode (FRED)

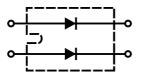
**DSEI 2x 101** 

 $V_{RRM} = 600 V$ 

 $I_{FAVM} = 2x 96 A$ 

 $t_{rr} = 35 \text{ ns}$ 

V <sub>RSM</sub>	V <sub>RRM</sub>	Туре
600	600	DSEI 2x 101-06A



miniBLOC, SOT-227 B E72873



Symbol	Symbol Test Conditions		Maximum Ratings (per diode)	
I <sub>F(RMS)</sub> I <sub>F(AV)M</sub> ① I <sub>FRM</sub>	$T_{VJ} = T_{VJM}$ $T_C = 70$ °C; rectangular, d = 0.5 $t_P < 10 \mu s$ ; rep. rating, pulse width li	150 96 mited by T <sub>VJM</sub> TBD	A A A	
I <sub>FSM</sub>	$T_{VJ} = 45$ °C; $t = 10$ ms (50 Hz), si $t = 8.3$ ms (60 Hz), si		A A	
	$T_{VJ} = 150$ °C; $t = 10$ ms (50 Hz), si $t = 8.3$ ms (60 Hz), si		A A	
l²t	$T_{VJ} = 45$ °C $t = 10$ ms (50 Hz), si $t = 8.3$ ms (60 Hz), si		A²s A²s	
	$T_{VJ} = 150$ °C; $t = 10$ ms (50 Hz), si $t = 8.3$ ms (60 Hz), si		A <sup>2</sup> s A <sup>2</sup> s	
T <sub>VJ</sub> T <sub>VJM</sub> T <sub>stg</sub>		-40+150 150 -40+150	°C °C °C	
P <sub>tot</sub>	T <sub>C</sub> = 25°C	250	W	
V <sub>ISOL</sub>	50/60 Hz, RMS I <sub>ISOL</sub> ≤ 1 mA	2500	V~	
M <sub>d</sub>	Mounting torque Terminal connection torque (M4)	1.5/13 1.5/13	Nm/lb.in. Nm/lb.in.	
Weight		30	g	

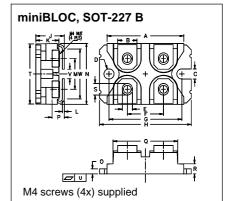
Symbol	Test Conditions Ch	aracteristic \	cteristic Values (per diode)	
		typ.	max.	
I <sub>R</sub>	$\begin{array}{lll} T_{VJ} = 25^{\circ}C & V_{R} &= V_{RRM} \\ T_{VJ} = 25^{\circ}C & V_{R} &= 0.8 \bullet V_{RRM} \\ T_{VJ} = 125^{\circ}C & V_{R} &= 0.8 \bullet V_{RRM} \end{array}$		3 1 20	mA mA mA
V <sub>F</sub>	$I_F = 100 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$		1.17 1.25	V V
$V_{T0}$ $r_{T}$	For power-loss calculations only		0.70 4.7	$\begin{matrix} V \\ m\Omega \end{matrix}$
$\begin{array}{c} {\rm R_{thJC}} \\ {\rm R_{thCH}} \end{array}$		0.05	0.5	K/W K/W
t <sub>rr</sub>	$I_F = 1$ A; -di/dt = 400 A/ $\mu$ s; $V_R = 30$ V; $T_{VJ} = 25$	°C 35	50	ns
I <sub>RM</sub>	$V_R$ = 100 V; $I_F$ = 80 A; -di_F/dt = 200 A/µs L $\leq$ 0.05 mH; $T_{VJ}$ = 100°C	19	24	Α

 $<sup>\</sup>oplus$  I  $_{_{FAVM}}$  rating includes reverse blocking losses at T  $_{_{VJM}},$  V  $_{_{R}}$  = 0.8 V  $_{_{RRM}},$  duty cycle d = 0.5 Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions

## **Features**

- International standard package
- miniBLOC (ISOTOP compatible)
- Isolation voltage 2500 V~
- matched diodes f. parallel operation
- · Planar passivated chips
- two independent diodes
- Very short recovery time
- Extremely low switching losses
- Low I<sub>RM</sub>-values
- Soft recovery behaviour



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
Α	31.50	31.88	1.240	1.255
В	7.80	8.20	0.307	0.323
С	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
Н	37.80	38.20	1.489	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.76	0.84	0.030	0.033
М	12.60	12.85	0.496	0.506
N	25.15	25.42	0.990	1.001
0	1.98	2.13	0.078	0.084
Р	4.95	5.97	0.195	0.235
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.174
S	4.72	4.85	0.186	0.191
Т	24.59	25.07	0.968	0.987
U	-0.05	0.1	-0.002	0.004
V	3.30	4.57	0.130	0.180
W	0.780	0.830	19.81	21.08

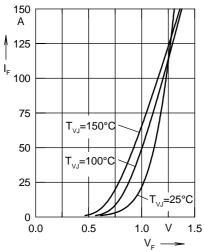


Fig. 1 Forward current I<sub>F</sub> versus V<sub>F</sub>

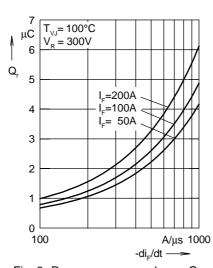


Fig. 2 Reverse recovery charge Q<sub>r</sub> versus -di<sub>F</sub>/dt

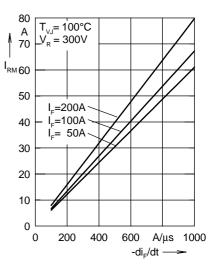


Fig. 3 Peak reverse current  $I_{\text{RM}}$  versus  $-\text{di}_{\text{F}}/\text{dt}$ 

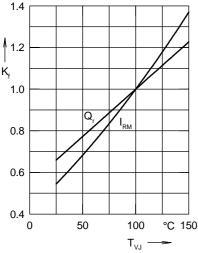


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$ 

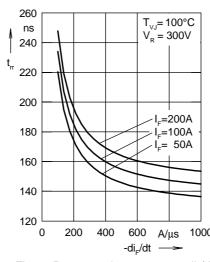


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_{F}/dt$ 

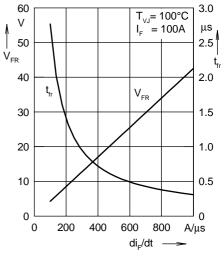


Fig. 6 Peak forward voltage  $\rm V_{FR}$  and  $\rm t_{fr}$  versus  $\rm di_{\it f}/dt$ 

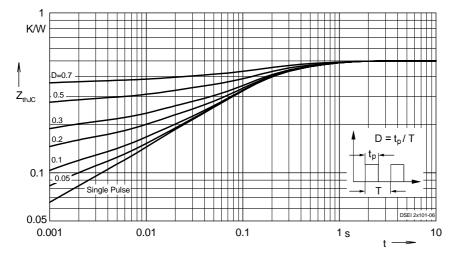


Fig. 7 Transient thermal impedance junction to case at various duty cycles

## Constants for $Z_{thJC}$ calculation:

i	R <sub>thi</sub> (K/W)	t <sub>i</sub> (s)
1	0.02	0.00002
2	0.05	0.00081
3	0.076	0.01
4	0.24	0.94
5	0.114	0.45